

f-33-11

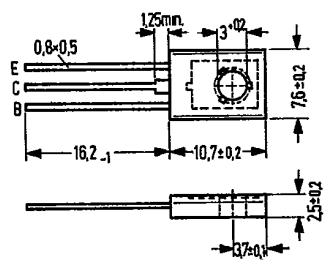
NPN Silicon Epibase Transistors

SIEMENS AKTIENGESELLSCHAFT

- BD 433
- BD 435
- BD 437
- BD 439
- BD 441

The transistors BD 433, BD 435, BD 437, BD 439, and BD 441 are NPN silicon epibase power transistors in TO 126 plastic package (12 A 3 DIN 41 869, sheet 4). The collector is electrically connected to the metallic mounting area. The transistors are particularly suitable for use in push-pull output stages, driver stages as well as for general AF applications. Their complementary types are the PNP transistors BD 434, BD 436, BD 438, BD 440, and BD 442.

| Type | Ordering code |
|----------------------|---------------|
| BD 433 | Q62702-D201 |
| BD 433/BD 434 paired | Q62702-D217 |
| BD 435 | Q62702-D203 |
| BD 435/BD 436 paired | Q62702-D218 |
| BD 437 | Q62702-D212 |
| BD 437/BD 438 paired | Q62702-D219 |
| BD 439 | Q62702-D280 |
| BD 439/BD 440 paired | Q62702-D284 |
| BD 441 | Q62702-D285 |
| BD 441/BD 442 paired | Q62702-D325 |
| Mica washer | Q62902-B62 |
| Spring washer | |
| A 3 DIN 137 | Q62902-B63 |



Approx. weight 0.5 g Dimensions in mm
 Transistor fixing with M 3 screw. Starting torque < 0.8 Nm, washer or spring washer should be used.
 1) If a 50 μ mica washer (ungreased) is used, the thermal resistance increases by 8 K/W and in case of a greased one by 4 K/W.

| Maximum ratings | BD 433 | BD 435 | BD 437 | BD 439 | BD 441 | |
|--|---------------------|-------------|--------|--------|--------|----|
| Collector-emitter voltage | V _{CEO} 22 | 32 | 45 | 60 | 80 | V |
| Collector-emitter voltage | V _{CES} 22 | 32 | 45 | 60 | 80 | V |
| Collector-base voltage | V _{CBO} 22 | 32 | 45 | 60 | 80 | V |
| Emitter-base voltage | V _{EBO} 5 | 5 | 5 | 5 | 5 | V |
| Collector current | I _C 4 | 4 | 4 | 4 | 4 | A |
| Collector peak current | I _{CM} 7 | 7 | 7 | 7 | 7 | A |
| Emitter peak current | I _{EM} 7 | 7 | 7 | 7 | 7 | A |
| Base current | I _B 1 | 1 | 1 | 1 | 1 | A |
| Junction temperature | T _J 150 | 150 | 150 | 150 | 150 | °C |
| Storage temperature range | T _{stg} | -55 to +150 | | | | °C |
| Total power dissipation (T _{case} ≤ 25°C; V _{CE} ≤ 12) | P _{tot} 36 | 36 | 36 | 36 | 36 | W |

| Thermal resistance | R _{thJA} | R _{thJC} | | | | |
|---------------------------|-------------------------|-------------------|-------|-------|-------|-----|
| Junction to ambient air | R _{thJA} ≤ 100 | ≤ 100 | ≤ 100 | ≤ 100 | ≤ 100 | K/W |
| Junction to mounting area | R _{thJC} ≤ 3,5 | ≤ 3,5 | ≤ 3,5 | ≤ 3,5 | ≤ 3,5 | K/W |

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Static characteristics ($T_{\text{case}} = 25^{\circ}\text{C}$)

| | BD 433 | BD 435 | BD 437 | BD 439 | BD 441 | |
|--|----------------------------------|---------|---------|---------|---------|---------------|
| Collector-emitter breakdown voltage ($I_C = 1000 \text{ mA}$) | $V_{(\text{BR})\text{CEO}} > 22$ | > 32 | > 45 | > 60 | > 80 | V |
| Collector-emitter breakdown voltage ($I_C = 100 \mu\text{A}$) | $V_{(\text{BR})\text{CES}} > 22$ | > 32 | > 45 | > 60 | > 80 | V |
| Collector-base breakdown voltage ($I_C = 100 \mu\text{A}$) | $V_{(\text{BR})\text{CBO}} > 22$ | > 32 | > 45 | > 60 | > 80 | V |
| Emitter-base breakdown voltage ($I_E = 1 \text{ mA}$) | $V_{(\text{BR})\text{EBO}} > 5$ | > 5 | > 5 | > 5 | > 5 | V |
| Collector cutoff current ($V_{\text{CB}} = 22 \text{ V}$) | $I_{\text{CBO}} < 100$ | - | - | - | - | μA |
| Collector cutoff current ($V_{\text{CB}} = 32 \text{ V}$) | $I_{\text{CBO}} -$ | < 100 | - | - | - | μA |
| Collector cutoff current ($V_{\text{CB}} = 45 \text{ V}$) | $I_{\text{CBO}} -$ | - | < 100 | - | - | μA |
| Collector cutoff current ($V_{\text{CB}} = 60 \text{ V}$) | $I_{\text{CBO}} -$ | - | - | < 100 | - | μA |
| Collector cutoff current ($V_{\text{CB}} = 80 \text{ V}$) | $I_{\text{CBO}} -$ | - | - | - | < 100 | μA |
| Collector cutoff current ($V_{\text{CB}} = 10 \text{ V}; T_{\text{amb}} = 150^{\circ}\text{C}$) | $I_{\text{CBO}} < 1$ | < 1 | < 1 | < 1 | < 1 | mA |
| Collector cutoff current ($V_{\text{CB}} = V_{\text{CB max}}; T_{\text{amb}} = 150^{\circ}\text{C}$) | $I_{\text{CBO}} < 3$ | < 3 | < 3 | < 3 | < 3 | mA |
| Base-emitter forward voltage ($I_C = 2 \text{ A}; V_{\text{CE}} = 1 \text{ V}$) | $V_{\text{BE}} < 1.1$ | < 1.1 | < 1.2 | < 1.5 | < 1.5 | V |
| Base-emitter forward voltage ($I_C = 3 \text{ A}; V_{\text{CE}} = 1 \text{ V}$) | $V_{\text{BE}} -$ | - | < 1.3 | < 1.6 | < 1.6 | V |
| Collector-emitter saturation voltage ($I_C = 2 \text{ A}$) ¹⁾ | $V_{\text{CEsat}} < 0.8$ | < 0.8 | - | - | - | V |
| Collector-emitter saturation spannung ($I_C = 2 \text{ A}; I_B = 0.2 \text{ A}$) | $V_{\text{CEsat}} < 0.5$ | < 0.5 | < 0.6 | < 0.8 | < 0.8 | V |
| Collector-emitter saturation voltage ($I_C = 3 \text{ A}; I_B = 0.3 \text{ A}$) | $V_{\text{CEsat}} -$ | - | < 0.7 | < 0.9 | < 0.9 | V |
| DC current gain ($I_C = 10 \text{ mA}; V_{\text{CE}} = 5 \text{ V}$) | $h_{\text{FE}} > 40$ | > 40 | > 30 | > 20 | > 15 | - |
| ($I_C = 500 \text{ mA}; V_{\text{CE}} = 1 \text{ V}$) ²⁾ | $h_{\text{FE}} > 85$ | > 85 | > 85 | > 40 | > 40 | - |
| ($I_C = 2 \text{ A}; V_{\text{CE}} = 1 \text{ V}$) | $h_{\text{FE}} > 50$ | > 50 | > 40 | > 25 | > 15 | - |

1) For the characteristic which passes through the point $I_C = 2.2 \text{ mA}$ and $V_{\text{CE}} = 1 \text{ V}$ at constant base current.2) Available as matching pairs with BD 434, BD 436, BD 438, BD 440, and BD 442. Condition for matching pairs $h_{\text{FE1}}/h_{\text{FE2}} \leq 1.41$.

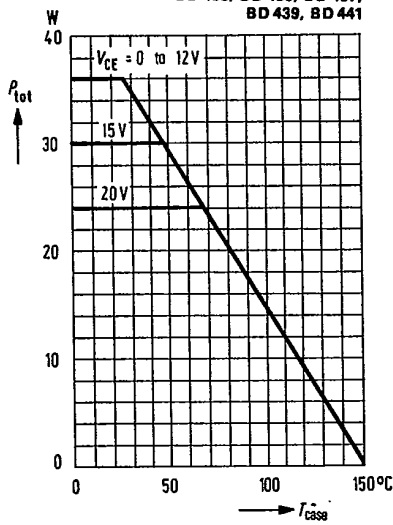
- BD 433
- BD 435
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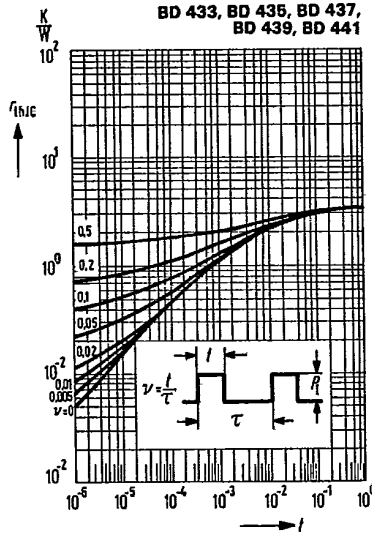
Dynamic characteristics ($T_{case} = 25^\circ C$)

| | BD 433 | BD 435 | BD 437 | BD 439 | BD 441 | |
|---|--------|--------|--------|--------|--------|-----|
| Transition frequency ($I_C = 0.25 A$; $V_{CE} = 1 V$; $f = 1 MHz$) | >3 | >3 | >3 | >3 | >3 | MHz |
| Cutoff frequency in common emitter configuration ($I_C = 0.25 A$; $V_{CE} = 1 V$) | >20 | >20 | >20 | >20 | >20 | kHz |

Total perm. power dissipation
 versus temperature
 $P_{tot} = f(T_{case})$; $V_{CE} = 0$ to $12 V$
 BD 433, BD 435, BD 437,
 BD 439, BD 441

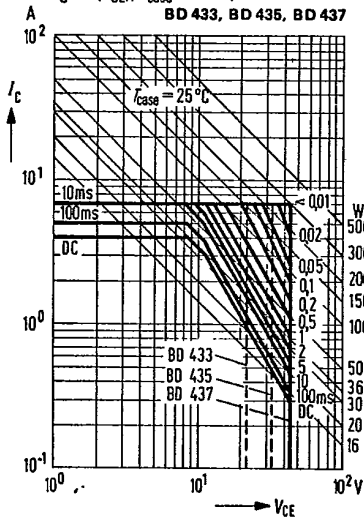


Permissible pulse load
 $r_{thJC} = f(t)$; $v =$ parameter
 BD 433, BD 435, BD 437,
 BD 439, BD 441

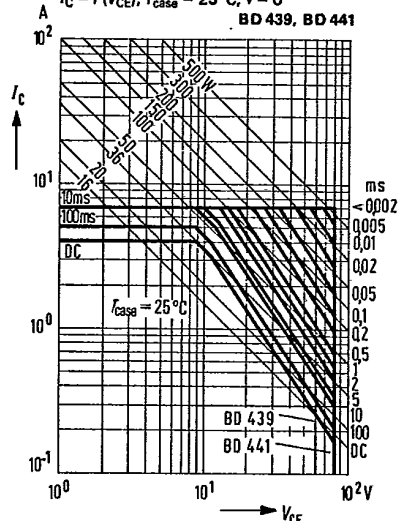


BD 433
 BD 435
 BD 437
 BD 439
 BD 441

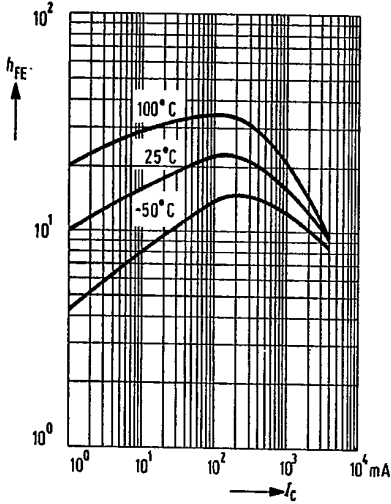
Permissible operating range
 $I_C = f(V_{CE})$; $T_{case} = 25^\circ C$, $v = 0$
 BD 433, BD 435, BD 437



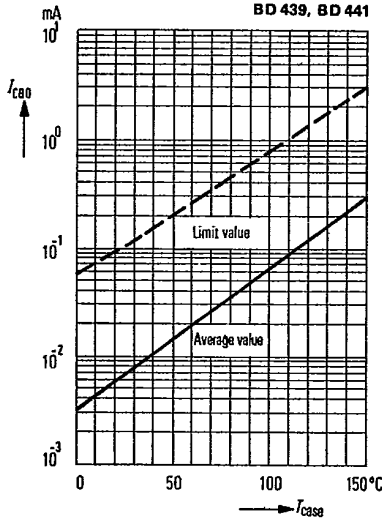
Permissible operating range
 $I_C = f(V_{CE})$; $T_{case} = 25^\circ C$, $v = 0$
 BD 439, BD 441



DC current gain $h_{FE} = f(I_C)$;
 $V_{CE} = 1V$; $T_{case} = \text{parameter}$
 BD 433, BD 435, BD 437,
 BD 439, BD 441



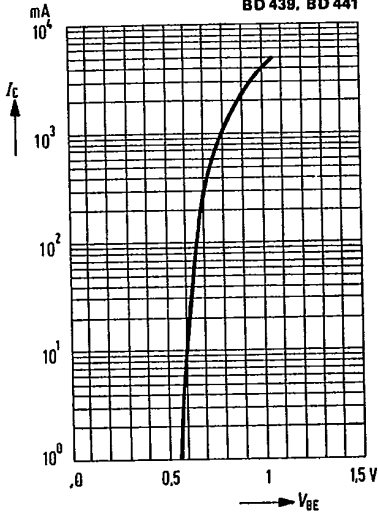
Collector cutoff current versus
 temperature $I_{CBO} = f(T_{case})$
 $V_{CB} = V_{Cemax}$
 BD 433, BD 435, BD 437,
 BD 439, BD 441



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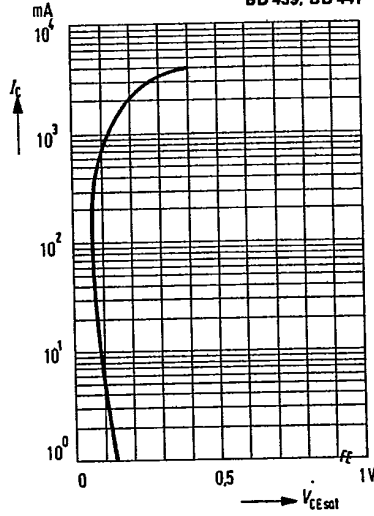
Collector current $I_C = f(V_{BE})$

$V_{CE} = 2\text{ V}; T_{\text{case}} = 25^\circ\text{C}$
 BD 433, BD 435, BD 437,
 BD 439, BD 441



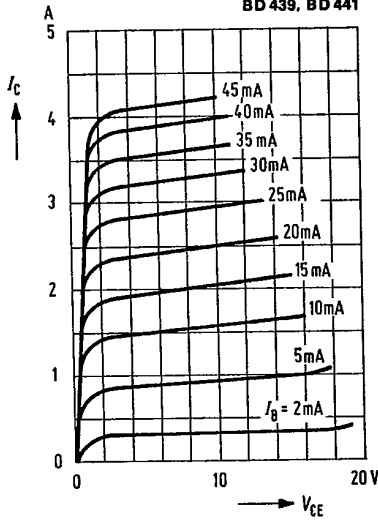
Collector-emitter saturation voltage

$V_{CE\text{sat}} = f(I_C); h_{FE} = 10; T_{\text{amb}} = 25^\circ\text{C}$
 BD 433, BD 435, BD 437,
 BD 439, BD 441



Output characteristics $I_C = f(V_{CE})$

$I_B = \text{parameter}$
 (common emitter configuration)
 BD 433, BD 435, BD 437,
 BD 439, BD 441



Transition frequency $f_T = f(I_C)$

$T_{\text{case}} = 25^\circ\text{C}$
 BD 433, BD 435, BD 437,
 BD 439, BD 441

